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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Applicant: Yi Ding
Assignee: ProMOS Technologies, Inc.
Title: Fabrication Of Gate Dielectric In Nonvolatile Memories In Which A Memory Cell Has Multiple Floating Gates
Application No.: 10/632,154 Filing Date: July 30, 2003
Examiner: Nguyen, Khiem D. Group Art Unit: 2823
Docket No.: M-15230 US

San Jose, California
May 31, 2005

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed except for United States Patents and United States Published Patent Applications.

Citation of these documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or
3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on May 31, 2005.

Michael Shenker
Michael Shenker
Attorney for Applicant

5-31-05
Date of Signature

Respectfully submitted,

Michael Shenker

Michael Shenker
Attorney for Applicant(s)
Reg. No. 34,250

U.S. Department of Commerce, Patent and Trademark Office				Atty Docket No.	Serial No.		
				M-15230 US	10/632,154		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Applicant			
(Use several sheets if necessary)				Yi Ding			
				Filing Date	Group		
				July 30, 2003	2823		
U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA	5,445,983	Aug. 1995	Hong			
	AB	5,633,185	May. 1997	Yiu et al.			
	AC	5,821,143	Oct. 1998	Kim et al.			
	AD	5,910,912	Jun. 1999	Hsu et al.			
	AE	5,918,124	Jun. 1999	Sung			
	AF	6,040,216	Mar. 2000	Sung			
	AG	6,107,141	Aug. 2000	Hsu et al.			
	AH	6,133,098	Oct. 2000	Ogura et al.			
	AI	6,187,636	Feb. 2001	Jeong			
	AJ	6,228,695	May. 2001	Hsieh et al.			
	AK	6,294,297	Sep. 2001	Chen			
	AL	6,436,764	Aug. 2002	Hsieh			
	AM	6,566,196	May-03	Haselden et al.			
	AN	6,635,533	Oct. 2003	Chang et al.			
	AO	6,642,103	Nov. 2003	Wils et al.			
	AP	6,660,589	Dec. 2003	Park			
	AQ	6,764,905	Jul. 2004	Jeng et al.			
	AR	6,803,276	Oct. 2004	Kim et al.			
	AS	4,701,776	Oct. 1987	Perlegos et al.			
	AT	5,408,115	Apr. 1995	Chang			
	AU	5,424,979	Jun. 1995	Morii			
	AV	6,011,725	Jan. 2002	Eitan			
	AW	6,388,293	May. 2002	Ogura et al.			
	AX	6,420,231	Jul. 2002	Harari et al.			
	AY						
	AZ						
Examiner		Date Considered					
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.							